

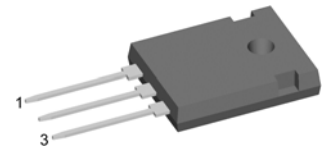
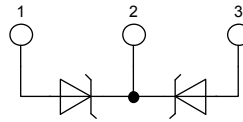
Schottky Diode

High Performance Schottky Diode
 Low Loss and Soft Recovery
 Common Cathode

$V_{RRM} = 100\text{ V}$
 $I_{FAV} = 2 \times 25\text{ A}$
 $V_F = 0.72\text{ V}$

Part number

DSA 50 C 100 HB



Backside: cathode

Features / Advantages:

- Very low V_f
- Extremely low switching losses
- low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

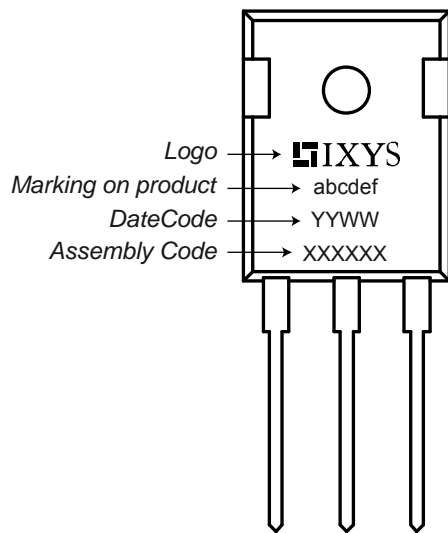
Package:

- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
V_{RRM}	max. repetitive reverse voltage				100	V
I_R	reverse current	$V_R = 100\text{ V}$			0.5	μA
		$V_R = 100\text{ V}$			5	mA
V_F	forward voltage	$I_F = 25\text{ A}$			0.90	V
		$I_F = 50\text{ A}$			1.07	V
		$I_F = 25\text{ A}$			0.72	V
		$I_F = 50\text{ A}$			0.90	V
I_{FAV}	average forward current	rectangular, $d = 0.5$			25	A
V_{FD}	threshold voltage	} for power loss calculation only			0.45	V
r_F	slope resistance				7.3	$\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				0.95	K/W
T_{VJ}	virtual junction temperature		-55		175	$^{\circ}\text{C}$
P_{tot}	total power dissipation				160	W
I_{FSM}	max. forward surge current	$t = 10\text{ ms}$ (50 Hz), sine			230	A
C_J	junction capacitance	$V_R = \text{tbd V}$; $f = 1\text{ MHz}$		tbd		pF
E_{AS}	non-repetitive avalanche energy	$I_{AS} = 10\text{ A}$; $L = 100\text{ }\mu\text{H}$			5	mJ
I_{AR}	repetitive avalanche current	$V_A = 1.5 \cdot V_R$ typ.; $f = 10\text{ kHz}$			1	A

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
I_{RMS}	RMS current	per pin ¹⁾			50	A
R_{thCH}	thermal resistance case to heatsink			0.25		K/W
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N

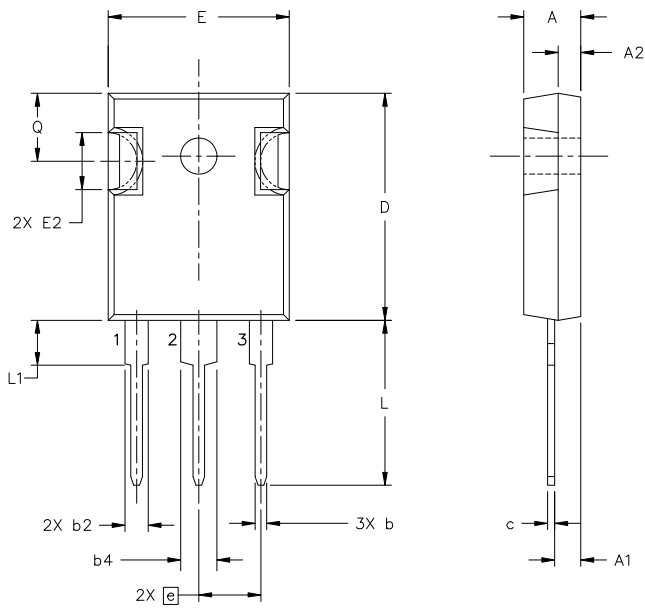
¹⁾ I_{RMS} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.
 In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

Product Marking

Part number

- D = Diode
- S = Schottky Diode
- A = low VF
- 50 = Current Rating [A]
- 100 = Reverse Voltage [V]
- HB = TO-247AD (3)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSA 50 C 100 HB	DSA50C100HB	Tube	50	502774

Outlines TO-247



Symbol	Inches		Millimeters	
	min	max	min	max
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215 BSC		5.46 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
ØP	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
ØP1	-	0.291	-	7.39